

Barium manganese(II) selenostannate(IV), BaMnSnSe₄

Abdeljalil Assoud, Bryan A. Kuropatwa and Holger Kleinke*

Department of Chemistry, Waterloo Institute for Nanotechnology, University of Waterloo, Waterloo, Ontario, Canada N2L 3G1
Correspondence e-mail: kleinke@uwaterloo.ca

Received 17 October 2011; accepted 8 November 2011

Key indicators: single-crystal X-ray study; $T = 298$ K; mean $\sigma(\text{Se-Mn}) = 0.002$ Å; R factor = 0.028; wR factor = 0.072; data-to-parameter ratio = 52.0.

The title compound, BaMnSnSe₄, was obtained by reaction of the elements at 1123 K in an evacuated silica tube. It adopts the BaCdSnS₄ structure type, which is a variant of the SrIn₂Se₄ structure type. Its structure consists of distorted edge-sharing tetrahedra, alternating with Mn and Sn atoms as central atom. These [MnSnSe₆] units display corner sharing, forming stacked infinite layers in the *ac* plane. The three different Ba²⁺ atoms are located between the [MnSnSe₆] layers, two on twofold rotation axes, and exhibit distorted square-antiprismatic coordinations.

Related literature

For the synthesis and structures of quaternary sulfides $A^{\text{II}}M^{\text{II}}B^{\text{IV}}S_4$ ($A^{\text{II}} = \text{Ba}$, $M^{\text{II}} = \text{Zn}$, Cd , Hg , Mn , $B^{\text{IV}} = \text{Ge}$, Sn), see: Teske (1980*a,b,c,d*). For the SrIn₂Se₄ structure type, see: Eisenmann & Hofmann (1991) and for the BaCdSnS₄ structure type, see: Assoud *et al.* (2004).

Experimental

Crystal data

BaMnSnSe₄

$M_r = 626.81$

Orthorhombic, *Fdd2*

$a = 22.3143$ (10) Å

$b = 22.7057$ (11) Å

$c = 13.4523$ (6) Å

$V = 6815.8$ (5) Å³

$Z = 32$

Mo $K\alpha$ radiation

$\mu = 25.93$ mm⁻¹

$T = 298$ K

$0.17 \times 0.13 \times 0.07$ mm

Data collection

Bruker SMART APEX CCD diffractometer

Absorption correction: multi-scan (*SADABS*; Sheldrick, 1996)

$T_{\text{min}} = 0.67$, $T_{\text{max}} = 0.97$

18387 measured reflections

6703 independent reflections

4800 reflections with $I > 2\sigma(I)$

$R_{\text{int}} = 0.031$

Refinement

$R[F^2 > 2\sigma(F^2)] = 0.028$

$wR(F^2) = 0.072$

$S = 1.13$

6703 reflections

129 parameters

1 restraint

$\Delta\rho_{\text{max}} = 1.95$ e Å⁻³

$\Delta\rho_{\text{min}} = -1.64$ e Å⁻³

Absolute structure: Flack (1983),

2823 Friedel pairs

Flack parameter: 0.044 (12)

Data collection: *SMART* (Bruker, 2000); cell refinement: *SAINTE* (Bruker, 1999); data reduction: *SAINTE*; program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *DIAMOND* (Brandenburg, 1999); software used to prepare material for publication: *SHELXL97*.

Financial support from the Natural Sciences and Engineering Research Council of Canada is gratefully acknowledged.

Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: RU2017).

References

- Assoud, A., Soheilnia, N. & Kleinke, H. (2004). *Chem. Mater.* **16**, 2215–2221.
Brandenburg, K. (1999). *DIAMOND*. Crystal Impact GbR, Bonn, Germany.
Bruker (1999). *SAINTE*. Bruker AXS Inc., Madison, Wisconsin, USA.
Bruker (2000). *SMART*. Bruker AXS Inc., Madison, Wisconsin, USA.
Eisenmann, B. & Hofmann, A. (1991). *Z. Kristallogr.* **197**, 167–168.
Flack, H. D. (1983). *Acta Cryst.* **A39**, 876–881.
Sheldrick, G. M. (1996). *SADABS*. University of Göttingen, Germany.
Sheldrick, G. M. (2008). *Acta Cryst.* **A64**, 112–122.
Teske, C. L. (1980*a*). *Z. Anorg. Allg. Chem.* **460**, 163–168.
Teske, C. L. (1980*b*). *Z. Anorg. Allg. Chem.* **468**, 27–34.
Teske, C. L. (1980*c*). *Z. Naturforsch. Teil B*, **35**, 7–11.
Teske, C. L. (1980*d*). *Z. Naturforsch. Teil B*, **35**, 509–510.

supplementary materials

Acta Cryst. (2011). E67, i72 [doi:10.1107/S1600536811047283]

Barium manganese(II) selenostannate(IV), BaMnSnSe₄

A. Assoud, B. A. Kuropatwa and H. Kleinke

Comment

A number of quaternary sulfides $A^{\text{II}}M^{\text{II}}B^{\text{IV}}\text{S}_4$ ($A^{\text{II}} = \text{Ba}$, $M^{\text{II}} = \text{Zn}$, Cd , Hg , Mn , $B^{\text{IV}} = \text{Ge}$, Sn) were synthesized and reported in 1980 (Teske, 1980*a,b,c,d*). They adopt the BaCdSnS₄ structure type and crystallize in the space group *Fdd2*, with the exception of BaHgSnS₄, which adopts the *Pnn2* group with the same structural motifs. These structures are variants of the SrIn₂Se₄ type (*Fddd*) (Eisenmann *et al.*, 1991) through the loss of the inversion centre due to the presence of two different M^{II} and B^{IV} centering cations. Here we report the synthesis and the crystal structure of the first selenide-based compound of this family, denoted BaMnSnSe₄.

One dark red block-like single-crystal of BaMnSnSe₄ was chosen under an optical microscope for study *via* single-crystal X-ray diffraction. The diffraction data were measured with the use of graphite-monochromated Mo—K α radiation on a BRUKER Smart APEX CCD diffractometer. Data were collected by scans of 0.3° in two groups of 606 frames at $\varphi = 0^\circ$ and 90° . The exposure times per frame were 40 s. The data were corrected for Lorentz and polarization effects. Absorption corrections were based on fitting a function to the empirical transmission surface as sampled by multiple equivalent measurements using *SADABS*.

The unit cell refinement gave an orthorhombic *F*-centered cell with $a = 22.3143$ (10) Å, $b = 22.7057$ (11) Å, $c = 13.4523$ (6) Å, $V = 6815.8$ (5) Å³. The structure refinement was performed using the SrSn₂Se₄ model, producing satisfying residual factors. The Ba atoms replaced Sr atoms, the tetravalent Sn3 and Sn4 atoms remained in the same Wyckoff positions and the divalent Sn1 and Sn2 of SrSn₂Se₄ were reassigned as Mn1 and Mn2, while the Se positions were retained.

The new selenide, BaMnSnSe₄ crystallizes in the BaCdSnS₄ structure type, which - as previously mentioned - is a variant of the SrIn₂Se₄ structure type (Eisenmann *et al.*, 1991). We present just a short summary of the principal features of the structure since it has since been described elsewhere (Assoud *et al.*, 2004; Eisenmann *et al.*, 1991; Teske, 1980*a,b,c,d*). Fig. 1 shows a unit cell projection along the *c*-axis.

In this structure, there are four crystallographically independent metal atom sites, namely Mn1, Mn2, Sn3 and Sn4, which are each tetrahedrally coordinated by Se atoms. The tetrahedra are severely distorted, with Se—Mn—Se and Se—Sn—Se angles between 96° and 126°. The Mn—Se and Sn—Se bonds vary from 2.50 Å to 2.61 Å and 2.49 Å to 2.54 Å, respectively. Similar distortions were observed in the case of the mixed valent selenostannate SrSn₂Se₄, in SrMgSnSe₄, (Assoud *et al.*, 2004) and in BaMSnS₄ ($M = \text{Mn}$, Zn , Cd , Hg) (Teske, 1980*a,b,c,d*), with Se—Sn—Se bond angles ranging from 94° to 129°. The tetrahedra in BaMnSnSe₄ are interconnected by sharing edges between the MnSe₄ and SnSe₄ units. These [MnSnSe₆] units then share corners with four identical units (two per tetrahedron) forming an infinite two-dimensional layer in the *ac* plane. The Ba atoms are in a square antiprismatic coordination, with Ba—Se bonds between 3.33 Å and 3.39 Å, occupying the space between the [MnSnSe₆]²⁻ layers. A single MnSnSe₄²⁻ layer is displayed in Fig. 2.

Experimental

The elements were acquired either in large blocks (Ba, 99.95% nominal purity, ALFA AESAR) or in powder form (Sn, 99.8%, -325 mesh, ALFA AESAR; Se, 99.5%, -100 mesh, Aldrich; Mn, 99.9%, -100 mesh, Aldrich). Because of the air sensitive nature of barium, all elements were handled in an argon-filled glove box. The elements were loaded in a silica tube (in 1:1:1:4 ratio), which was evacuated and sealed under dynamic vacuum, then placed into a temperature controlled resistance furnace. The silica tube was heated to 850°C within 24 h, kept at 850°C for a period of 4 days, and then cooled to 200°C within 8 days. Thereafter, the furnace was turned off. The samples looked homogeneous, comprising mostly microcrystalline red powder.

Refinement

(type here to add refinement details)

Figures

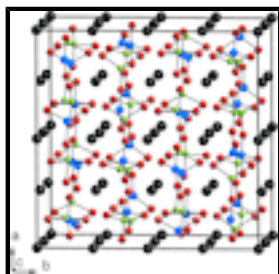


Fig. 1. Crystal structure of BaMnSnSe₄ in a projection along the *c* axis. Black: Ba; green: Mn; blue: Sn; red: Se.

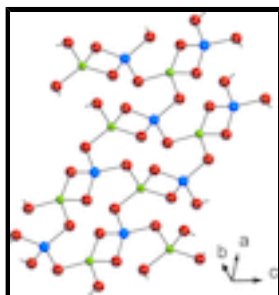


Fig. 2. A single MnSnSe₄²⁻ layer of the structure of BaMnSnSe₄. Green: Mn; blue: Sn; red: Se.

Barium manganese(II) selenostannate(IV)

Crystal data

BaMnSnSe₄

$M_r = 626.81$

Orthorhombic, *Fdd2*

$a = 22.3143 (10) \text{ \AA}$

$b = 22.7057 (11) \text{ \AA}$

$c = 13.4523 (6) \text{ \AA}$

$V = 6815.8 (5) \text{ \AA}^3$

$Z = 32$

$D_x = 4.887 \text{ Mg m}^{-3}$

Mo $K\alpha$ radiation, $\lambda = 0.71073 \text{ \AA}$

Cell parameters from 1000 reflections

$\theta = 2.0\text{--}35^\circ$

$\mu = 25.93 \text{ mm}^{-1}$

$T = 298 \text{ K}$

Block, red

$0.17 \times 0.13 \times 0.07 \text{ mm}$

$F(000) = 8544$

Data collection

Bruker SMART APEX CCD diffractometer	6703 independent reflections
Radiation source: fine-focus sealed tube	4800 reflections with $I > 2\sigma(I)$
graphite	$R_{\text{int}} = 0.031$
ω scans	$\theta_{\text{max}} = 35.0^\circ$, $\theta_{\text{min}} = 2.0^\circ$
Absorption correction: multi-scan (SADABS; Sheldrick, 1996)	$h = -35 \rightarrow 35$
$T_{\text{min}} = 0.67$, $T_{\text{max}} = 0.97$	$k = -32 \rightarrow 36$
18387 measured reflections	$l = -21 \rightarrow 16$

Refinement

Refinement on F^2	Secondary atom site location: difference Fourier map
Least-squares matrix: full	$w = 1/[\sigma^2(F_o^2) + (0.0177P)^2 + 37.4914P]$
	where $P = (F_o^2 + 2F_c^2)/3$
$R[F^2 > 2\sigma(F^2)] = 0.028$	$(\Delta/\sigma)_{\text{max}} = 0.001$
$wR(F^2) = 0.072$	$\Delta\rho_{\text{max}} = 1.95 \text{ e } \text{\AA}^{-3}$
$S = 1.13$	$\Delta\rho_{\text{min}} = -1.64 \text{ e } \text{\AA}^{-3}$
6703 reflections	Extinction correction: <i>SHELXL97</i> (Sheldrick, 2008), $F_c^* = kFc[1 + 0.001 \times Fc^2 \lambda^3 / \sin(2\theta)]^{-1/4}$
129 parameters	Extinction coefficient: 0.0000363 (16)
1 restraint	Absolute structure: Flack (1983), 2823 Friedel pairs
Primary atom site location: structure-invariant direct methods	Flack parameter: 0.044 (12)

Special details

Geometry. All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted R -factor wR and goodness of fit S are based on F^2 , conventional R -factors R are based on F , with F set to zero for negative F^2 . The threshold expression of $F^2 > 2\sigma(F^2)$ is used only for calculating R -factors(gt) *etc.* and is not relevant to the choice of reflections for refinement. R -factors based on F^2 are statistically about twice as large as those based on F , and R -factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (\AA^2)

	x	y	z	$U_{\text{iso}}^*/U_{\text{eq}}$
Ba1	0.5000	0.0000	0.51434 (7)	0.01461 (15)
Ba2	0.2500	0.2500	0.76741 (7)	0.01464 (14)
Ba3	0.498642 (19)	0.252102 (14)	0.51495 (6)	0.01478 (13)
Mn1	0.42578 (5)	0.12560 (6)	0.80278 (9)	0.0199 (2)

supplementary materials

Mn2	0.38807 (5)	0.12366 (6)	0.26964 (9)	0.0198 (2)
Sn3	0.36418 (2)	0.12530 (3)	0.51561 (4)	0.01241 (9)
Sn4	0.56889 (2)	0.12516 (3)	0.22465 (4)	0.01295 (9)
Se1	0.45804 (3)	0.12557 (5)	0.62286 (5)	0.01312 (14)
Se2	0.37358 (3)	0.03939 (4)	0.89544 (8)	0.01486 (19)
Se3	0.37316 (3)	0.21127 (4)	0.89774 (8)	0.0156 (2)
Se4	0.28052 (3)	0.12657 (5)	0.63900 (6)	0.01672 (14)
Se5	0.46781 (3)	0.12444 (5)	0.13819 (6)	0.01467 (15)
Se6	0.37314 (4)	0.20988 (4)	0.39409 (7)	0.0160 (2)
Se7	0.37225 (4)	0.03902 (4)	0.39730 (7)	0.01519 (19)
Se8	0.54326 (3)	0.12649 (5)	0.40527 (6)	0.01468 (13)

Atomic displacement parameters (\AA^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
Ba1	0.0128 (3)	0.0114 (3)	0.0196 (4)	0.0003 (3)	0.000	0.000
Ba2	0.0142 (3)	0.0128 (3)	0.0169 (4)	0.0001 (3)	0.000	0.000
Ba3	0.0134 (2)	0.0122 (2)	0.0188 (4)	-0.0004 (2)	0.00082 (10)	-0.00034 (18)
Mn1	0.0209 (5)	0.0239 (6)	0.0148 (6)	-0.0002 (5)	0.0049 (4)	0.0000 (5)
Mn2	0.0183 (4)	0.0271 (6)	0.0141 (6)	-0.0004 (5)	0.0029 (4)	0.0001 (6)
Sn3	0.01249 (14)	0.0135 (2)	0.0113 (2)	0.00023 (18)	0.00052 (16)	0.0000 (2)
Sn4	0.01337 (17)	0.0137 (2)	0.0118 (2)	0.00020 (16)	0.00104 (15)	0.00006 (19)
Se1	0.0133 (2)	0.0150 (4)	0.0111 (4)	0.0002 (3)	0.0004 (2)	0.0001 (4)
Se2	0.0131 (4)	0.0128 (5)	0.0187 (5)	0.0012 (2)	-0.0017 (4)	-0.0018 (3)
Se3	0.0142 (4)	0.0134 (5)	0.0192 (5)	-0.0018 (2)	-0.0021 (4)	0.0019 (3)
Se4	0.0161 (3)	0.0176 (3)	0.0164 (4)	-0.0001 (3)	0.0056 (3)	0.0003 (4)
Se5	0.0129 (3)	0.0175 (4)	0.0136 (4)	-0.0002 (3)	0.0017 (2)	0.0000 (4)
Se6	0.0183 (5)	0.0133 (5)	0.0165 (5)	-0.0007 (3)	-0.0050 (4)	0.0024 (3)
Se7	0.0166 (4)	0.0129 (5)	0.0160 (5)	0.0007 (3)	-0.0039 (4)	-0.0021 (3)
Se8	0.0172 (2)	0.0150 (3)	0.0119 (3)	0.0007 (3)	0.0025 (2)	-0.0003 (4)

Geometric parameters (\AA , $^\circ$)

Ba1—Se1 ⁱ	3.3373 (11)	Mn1—Se3	2.6067 (17)
Ba1—Se1	3.3373 (11)	Mn1—Se4 ⁱⁱ	2.6097 (13)
Ba1—Se8 ⁱ	3.3664 (11)	Mn2—Se5	2.5086 (14)
Ba1—Se8	3.3664 (11)	Mn2—Se6	2.5974 (18)
Ba1—Se7	3.3748 (9)	Mn2—Se7	2.6014 (17)
Ba1—Se7 ⁱ	3.3748 (9)	Mn2—Se8 ^{vii}	2.6160 (14)
Ba1—Se6 ⁱⁱ	3.3804 (10)	Sn3—Se4	2.4982 (8)
Ba1—Se6 ⁱⁱⁱ	3.3804 (10)	Sn3—Se6	2.5299 (12)
Ba2—Se5 ^{iv}	3.3375 (12)	Sn3—Se7	2.5304 (11)
Ba2—Se5 ^v	3.3375 (12)	Sn3—Se1	2.5431 (8)
Ba2—Se4	3.3619 (12)	Sn4—Se8	2.4963 (10)
Ba2—Se4 ^{vi}	3.3620 (12)	Sn4—Se3 ^{xi}	2.5276 (11)
Ba2—Se3 ^{vi}	3.3764 (10)	Sn4—Se2 ^{xi}	2.5277 (11)
Ba2—Se3	3.3765 (10)	Sn4—Se5	2.5377 (7)

Ba2—Se2 ^{vii}	3.3838 (9)	Se2—Sn4 ^v	2.5276 (11)
Ba2—Se2 ^{viii}	3.3838 (9)	Se2—Ba3 ⁱⁱⁱ	3.3520 (10)
Ba3—Se5 ^{ix}	3.3417 (12)	Se2—Ba2 ⁱⁱ	3.3838 (9)
Ba3—Se1	3.3440 (11)	Se3—Sn4 ^v	2.5275 (11)
Ba3—Se2 ^{viii}	3.3521 (10)	Se3—Ba3 ^{ix}	3.3705 (10)
Ba3—Se4 ^{viii}	3.3587 (12)	Se4—Mn1 ^{vii}	2.6097 (13)
Ba3—Se8	3.3619 (11)	Se4—Ba3 ⁱⁱⁱ	3.3586 (12)
Ba3—Se3 ^x	3.3706 (10)	Se5—Ba2 ^{xi}	3.3375 (12)
Ba3—Se6	3.3772 (10)	Se5—Ba3 ^x	3.3416 (12)
Ba3—Se7 ⁱⁱ	3.4132 (10)	Se6—Ba1 ^{vii}	3.3804 (10)
Mn1—Se1	2.5251 (15)	Se7—Ba3 ^{vii}	3.4133 (10)
Mn1—Se2	2.5965 (17)	Se8—Mn2 ⁱⁱ	2.6160 (14)
Se1 ⁱ —Ba1—Se1	128.12 (4)	Se1—Ba3—Se7 ⁱⁱ	75.97 (2)
Se1 ⁱ —Ba1—Se8 ⁱ	62.758 (16)	Se2 ^{viii} —Ba3—Se7 ⁱⁱ	116.97 (3)
Se1—Ba1—Se8 ⁱ	147.042 (13)	Se4 ^{viii} —Ba3—Se7 ⁱⁱ	130.54 (2)
Se1 ⁱ —Ba1—Se8	147.044 (13)	Se8—Ba3—Se7 ⁱⁱ	75.97 (2)
Se1—Ba1—Se8	62.757 (16)	Se3 ^x —Ba3—Se7 ⁱⁱ	68.02 (3)
Se8 ⁱ —Ba1—Se8	128.32 (4)	Se6—Ba3—Se7 ⁱⁱ	147.523 (18)
Se1 ⁱ —Ba1—Se7	131.71 (2)	Se1—Mn1—Se2	126.01 (6)
Se1—Ba1—Se7	75.09 (2)	Se1—Mn1—Se3	126.75 (7)
Se8 ⁱ —Ba1—Se7	77.20 (2)	Se2—Mn1—Se3	97.19 (5)
Se8—Ba1—Se7	79.33 (2)	Se1—Mn1—Se4 ⁱⁱ	99.83 (4)
Se1 ⁱ —Ba1—Se7 ⁱ	75.10 (2)	Se2—Mn1—Se4 ⁱⁱ	100.04 (5)
Se1—Ba1—Se7 ⁱ	131.71 (2)	Se3—Mn1—Se4 ⁱⁱ	101.51 (5)
Se8 ⁱ —Ba1—Se7 ⁱ	79.33 (2)	Se5—Mn2—Se6	122.69 (6)
Se8—Ba1—Se7 ⁱ	77.20 (2)	Se5—Mn2—Se7	124.52 (6)
Se7—Ba1—Se7 ⁱ	124.38 (4)	Se6—Mn2—Se7	96.54 (5)
Se1 ⁱ —Ba1—Se6 ⁱⁱ	77.07 (2)	Se5—Mn2—Se8 ^{vii}	99.15 (5)
Se1—Ba1—Se6 ⁱⁱ	76.82 (2)	Se6—Mn2—Se8 ^{vii}	106.04 (5)
Se8 ⁱ —Ba1—Se6 ⁱⁱ	133.47 (2)	Se7—Mn2—Se8 ^{vii}	106.12 (5)
Se8—Ba1—Se6 ⁱⁱ	76.24 (2)	Se4—Sn3—Se6	118.66 (4)
Se7—Ba1—Se6 ⁱⁱ	148.952 (15)	Se4—Sn3—Se7	118.69 (4)
Se7 ⁱ —Ba1—Se6 ⁱⁱ	67.98 (2)	Se6—Sn3—Se7	100.12 (4)
Se1 ⁱ —Ba1—Se6 ⁱⁱⁱ	76.82 (2)	Se4—Sn3—Se1	103.79 (3)
Se1—Ba1—Se6 ⁱⁱⁱ	77.07 (2)	Se6—Sn3—Se1	107.44 (4)
Se8 ⁱ —Ba1—Se6 ⁱⁱⁱ	76.24 (2)	Se7—Sn3—Se1	107.46 (3)
Se8—Ba1—Se6 ⁱⁱⁱ	133.47 (2)	Se8—Sn4—Se3 ^{xi}	121.17 (4)
Se7—Ba1—Se6 ⁱⁱⁱ	67.98 (2)	Se8—Sn4—Se2 ^{xi}	120.77 (4)
Se7 ⁱ —Ba1—Se6 ⁱⁱⁱ	148.952 (15)	Se3 ^{xi} —Sn4—Se2 ^{xi}	101.07 (3)
Se6 ⁱⁱ —Ba1—Se6 ⁱⁱⁱ	117.82 (4)	Se8—Sn4—Se5	104.04 (3)
Se5 ^{iv} —Ba2—Se5 ^v	121.73 (4)	Se3 ^{xi} —Sn4—Se5	103.49 (4)

supplementary materials

Se5 ^{iv} —Ba2—Se4	155.821 (13)	Se2 ^{xi} —Sn4—Se5	103.94 (4)
Se5 ^v —Ba2—Se4	65.669 (17)	Mn1—Se1—Sn3	108.00 (4)
Se5 ^{iv} —Ba2—Se4 ^{vi}	65.669 (17)	Mn1—Se1—Ba1	119.97 (5)
Se5 ^v —Ba2—Se4 ^{vi}	155.821 (13)	Sn3—Se1—Ba1	88.90 (3)
Se4—Ba2—Se4 ^{vi}	118.17 (4)	Mn1—Se1—Ba3	119.55 (5)
Se5 ^{iv} —Ba2—Se3 ^{vi}	72.66 (2)	Sn3—Se1—Ba3	88.79 (3)
Se5 ^v —Ba2—Se3 ^{vi}	78.02 (3)	Ba1—Se1—Ba3	117.91 (3)
Se4—Ba2—Se3 ^{vi}	130.45 (2)	Sn4 ^v —Se2—Mn1	80.81 (4)
Se4 ^{vi} —Ba2—Se3 ^{vi}	83.38 (2)	Sn4 ^v —Se2—Ba3 ⁱⁱⁱ	91.25 (3)
Se5 ^{iv} —Ba2—Se3	78.03 (3)	Mn1—Se2—Ba3 ⁱⁱⁱ	107.70 (4)
Se5 ^v —Ba2—Se3	72.66 (2)	Sn4 ^v —Se2—Ba2 ⁱⁱ	113.64 (4)
Se4—Ba2—Se3	83.38 (2)	Mn1—Se2—Ba2 ⁱⁱ	93.33 (3)
Se4 ^{vi} —Ba2—Se3	130.45 (2)	Ba3 ⁱⁱⁱ —Se2—Ba2 ⁱⁱ	149.93 (3)
Se3 ^{vi} —Ba2—Se3	117.43 (4)	Sn4 ^v —Se3—Mn1	80.62 (4)
Se5 ^{iv} —Ba2—Se2 ^{vii}	129.74 (2)	Sn4 ^v —Se3—Ba3 ^{ix}	114.00 (4)
Se5 ^v —Ba2—Se2 ^{vii}	80.38 (2)	Mn1—Se3—Ba3 ^{ix}	91.78 (3)
Se4—Ba2—Se2 ^{vii}	72.51 (2)	Sn4 ^v —Se3—Ba2	91.42 (3)
Se4 ^{vi} —Ba2—Se2 ^{vii}	78.60 (2)	Mn1—Se3—Ba2	107.85 (4)
Se3 ^{vi} —Ba2—Se2 ^{vii}	69.03 (2)	Ba3 ^{ix} —Se3—Ba2	150.40 (3)
Se3—Ba2—Se2 ^{vii}	149.488 (14)	Sn3—Se4—Mn1 ^{vii}	111.94 (4)
Se5 ^{iv} —Ba2—Se2 ^{viii}	80.38 (2)	Sn3—Se4—Ba3 ⁱⁱⁱ	118.05 (4)
Se5 ^v —Ba2—Se2 ^{viii}	129.74 (2)	Mn1 ^{vii} —Se4—Ba3 ⁱⁱⁱ	92.00 (4)
Se4—Ba2—Se2 ^{viii}	78.60 (2)	Sn3—Se4—Ba2	120.16 (4)
Se4 ^{vi} —Ba2—Se2 ^{viii}	72.51 (2)	Mn1 ^{vii} —Se4—Ba2	93.59 (4)
Se3 ^{vi} —Ba2—Se2 ^{viii}	149.489 (15)	Ba3 ⁱⁱⁱ —Se4—Ba2	113.76 (3)
Se3—Ba2—Se2 ^{viii}	69.03 (2)	Mn2—Se5—Sn4	107.90 (4)
Se2 ^{vii} —Ba2—Se2 ^{viii}	121.99 (4)	Mn2—Se5—Ba2 ^{xi}	119.33 (5)
Se5 ^{ix} —Ba3—Se1	124.48 (3)	Sn4—Se5—Ba2 ^{xi}	92.14 (3)
Se5 ^{ix} —Ba3—Se2 ^{viii}	73.18 (2)	Mn2—Se5—Ba3 ^x	120.96 (5)
Se1—Ba3—Se2 ^{viii}	76.66 (2)	Sn4—Se5—Ba3 ^x	91.31 (3)
Se5 ^{ix} —Ba3—Se4 ^{viii}	65.659 (18)	Ba2 ^{xi} —Se5—Ba3 ^x	114.86 (3)
Se1—Ba3—Se4 ^{viii}	152.79 (2)	Sn3—Se6—Mn2	81.63 (4)
Se2 ^{viii} —Ba3—Se4 ^{viii}	83.91 (2)	Sn3—Se6—Ba3	88.28 (3)
Se5 ^{ix} —Ba3—Se8	149.66 (2)	Mn2—Se6—Ba3	114.70 (4)
Se1—Ba3—Se8	62.735 (17)	Sn3—Se6—Ba1 ^{vii}	118.29 (3)
Se2 ^{viii} —Ba3—Se8	133.24 (2)	Mn2—Se6—Ba1 ^{vii}	88.54 (4)
Se4 ^{viii} —Ba3—Se8	123.35 (3)	Ba3—Se6—Ba1 ^{vii}	147.80 (3)
Se5 ^{ix} —Ba3—Se3 ^x	80.50 (2)	Sn3—Se7—Mn2	81.55 (4)
Se1—Ba3—Se3 ^x	130.17 (2)	Sn3—Se7—Ba1	88.28 (3)
Se2 ^{viii} —Ba3—Se3 ^x	150.829 (18)	Mn2—Se7—Ba1	112.79 (4)
Se4 ^{viii} —Ba3—Se3 ^x	73.79 (2)	Sn3—Se7—Ba3 ^{vii}	118.84 (3)

Se8—Ba3—Se3 ^x	75.68 (2)	Mn2—Se7—Ba3 ^{vii}	88.13 (4)
Se5 ^{ix} —Ba3—Se6	131.51 (2)	Ba1—Se7—Ba3 ^{vii}	148.66 (3)
Se1—Ba3—Se6	74.95 (2)	Sn4—Se8—Mn2 ⁱⁱ	112.78 (4)
Se2 ^{viii} —Ba3—Se6	69.46 (3)	Sn4—Se8—Ba3	120.35 (4)
Se4 ^{viii} —Ba3—Se6	80.52 (2)	Mn2 ⁱⁱ —Se8—Ba3	89.00 (4)
Se8—Ba3—Se6	78.08 (2)	Sn4—Se8—Ba1	118.66 (4)
Se3 ^x —Ba3—Se6	123.27 (4)	Mn2 ⁱⁱ —Se8—Ba1	88.53 (4)
Se5 ^{ix} —Ba3—Se7 ⁱⁱ	77.86 (2)	Ba3—Se8—Ba1	116.59 (3)

Symmetry codes: (i) $-x+1, -y, z$; (ii) $x+1/4, -y+1/4, z+1/4$; (iii) $-x+3/4, y-1/4, z+1/4$; (iv) $-x+3/4, y+1/4, z+3/4$; (v) $x-1/4, -y+1/4, z+3/4$; (vi) $-x+1/2, -y+1/2, z$; (vii) $x-1/4, -y+1/4, z-1/4$; (viii) $-x+3/4, y+1/4, z-1/4$; (ix) $-x+1, -y+1/2, z+1/2$; (x) $-x+1, -y+1/2, z-1/2$; (xi) $x+1/4, -y+1/4, z-3/4$.

Fig. 1

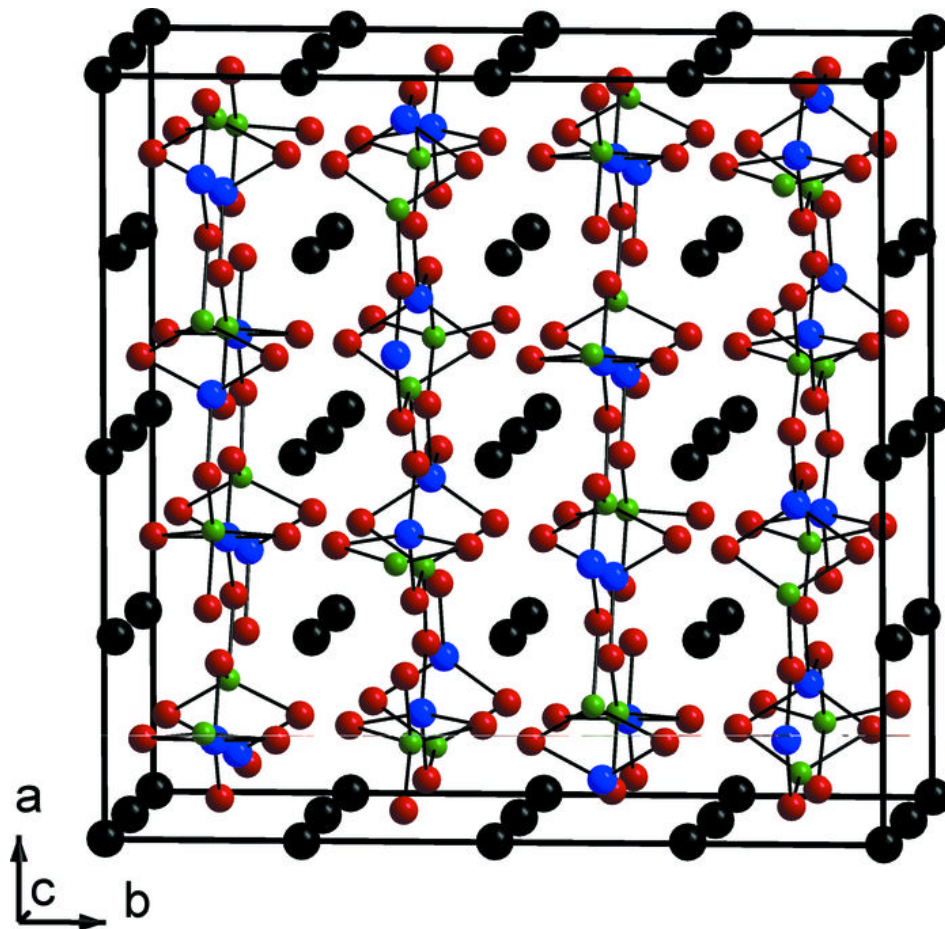


Fig. 2

